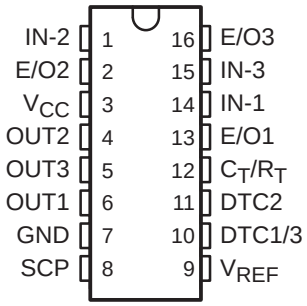
- **Low Voltage Operation . . . 2.5 V to 7 V**
- **Low Power . . . 3. 5 mA (f = 500 kHz, Duty = 50%)**
- **Internal Undervoltage Lockout Protection**
- **Internal Short Circuit Protection**
- **Wide Operating Frequency . . . 50 kHz to 1 MHz**
- **Internal Precision Reference . . . 1.25 V ±1% (25°C)**
- **On/Off Switch for CH1/3 Pair and Ch2 (see Function Table)**
- **0 to 100% Dead Time Control**
- **Totem Pole Output Stage**
- **Smal l Package . . . 16 Pin TSSOP**

PW PACKAGE
(TOP VIEW)



description

The TPS5100 is a triple PWM control circuit, primarily designed to compose the power supply for LCD display. Each PWM channel has own error amplifier, PWM comparator, dead-time control and output driver. The trimmed voltage reference, oscillator, undervoltage lockout and short circuit protection are common for all channels.

This device includes two boost exclusive circuits (ch1,3) and a buck-boost exclusive circuit (ch2). The operating frequency is set with external resister and capacitor, and dead time is continuously adjustable form 0% to 100% duty cycle with resistive divider network. Soft start function can be implemented by adding a capacitor to dead time divider network. Two dead time control inputs are assigned for ch1,3 pair and ch2 individually and each dead time control input can be used to control on/off operation. TPS5100 can operate from 2.5 V supply voltage and ch1,3 pair and ch2 operate with reverse phase switching each other to achieve efficient operation in low power and battery powered system.

The TPS5100 is characterized for operation from –20°C to 85°C.

FUNCTION TABLE

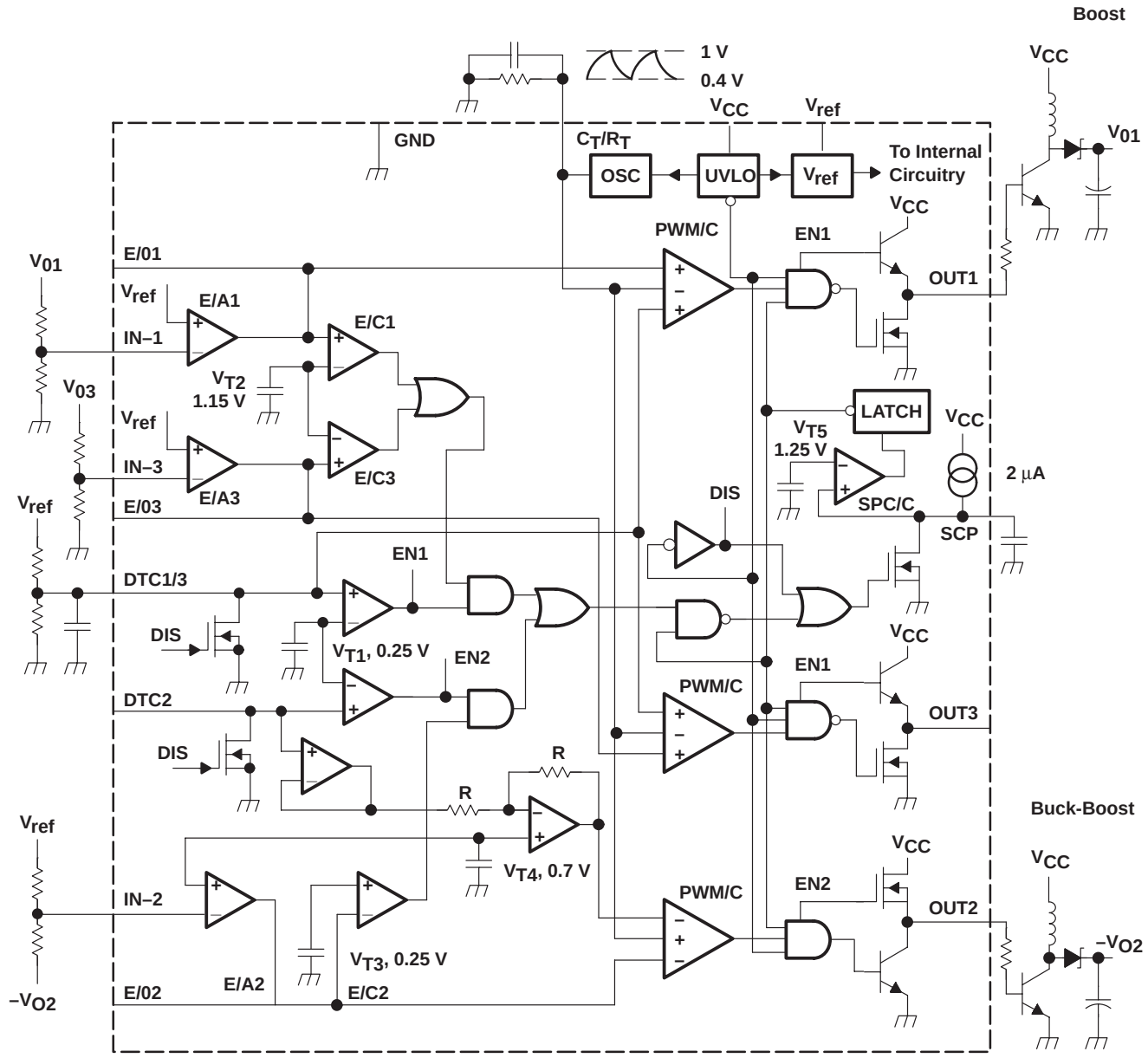
CONDITION	OUTPUT		
	CH-1	CH-2	CH-3
DTC1/3 >. 0.3 V, DTC2 > 0.3 V	ON H	ON L	ON H
DTC1/3 > 0.3 V, DTC2 <. 0.2 V	ON H	OFF H	ON H
DTC1/3 < 0.2 V, DTC2 > 0.3 V	OFF L	ON L	OFF L
DTC1/3 < 0.2 V, DTC2 < 0.2 V	OFF L	OFF H	OFF L

AVAILABLE OPTIONS

T_A	PACKAGE
	TSSOP (PW)
–20°C to 85°C	TPS5100PW

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

functional block diagram



NOTE A: All voltages and currents listed are nominal.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V (unless otherwise noted) (see Note 1)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{REF}	Reference voltage	I_{REF} = –1 mA,	T_A = 25°C	1.237	1.250	1.263	V
$V_{REF(dev)}$	Reference voltage change with T_A	I_{REF} = –1 mA,	See Note 2		15	25	mV
R_{EGIN}	Input regulation	I_{REF} = –1 mA,	V_{CC} = 2.5 V to 7 V		2	5	mV
R_{EGL}	Output regulation	I_{REF} = –0.1 mA to –1 mA			1	5	mV
I_{OS}	Short-circuit output current	V_{REF} = 0		–2	–10	–30	mA

NOTES: 1. Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.
2. The deviation parameter $V_{REF(dev)}$ is defined as the difference between the maximum and minimum values obtained over the recommended free-air temperature range (–20°C to 85°C).

undervoltage lockout section

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{TH}	Upper threshold voltage	T_A = 25°C	2.2	2.3	2.4	V
V_{TL}	Lower threshold voltage	T_A = 25°C	2	2.1	2.2	V
V_{hys}	Hysteresis ($V_{TH} – V_{TL}$)	T_A = 25°C	0.1	0.2	0.3	V

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

protection control section

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{SCP}	Input terminal source current		–1.4	–2	–2.6	µA
V_{T2}	Input threshold voltage	CH-1, 3	1.10	1.15	1.20	V
V_{T3}		CH-2	0.20	0.25	0.30	
V_R	Latch reset threshold voltage	T_A = 25°C	0.8	1.5		V
V_{T5}	Threshold voltage		1.20	1.25	1.30	V

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

oscillator section

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
f_{OSC}	Frequency	C_T = 130 pF,	R_T = 7 kΩ	400	500	600	kHz
f_{dV}	Frequency change with V_{CC}	V_{CC} = 2.5 V, C_T = 130 pF,	T_A = 25°C, R_T = 7 kΩ		1%	2%	
f_{dT}	Frequency change with T_A	C_T = 130 pF,	R_T = 7 kΩ		5%	10%	
$I_{CT/RT}$	Output source current			–180	–200	–220	µA
V_{OSCH}	H level output voltage			0.95	1	1.05	V
V_{OSCL}	L level output voltage			0.35	0.40	0.45	V

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

dead time control section

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$I_{BDT1/3}$	Input bias current	$V_{DTC1/3}$ = 0.35 V to 1.05 V				200	nA
I_{BDT2}		V_{DTC2} = 0.35 V to 1.05 V			±2	±20	
V_{T1}	Comparator threshold voltage			0.2	0.25	0.3	V
$V_{T0(DTC1/3)}$	Input threshold voltage (DTC1/3) (see Note 3)	Duty = 0%	f_{OSC} = 500 kHz	0.3	0.4	0.5	V
$V_{T100(DTC1/3)}$		Duty = 100%		0.9	1	1.1	
$V_{T0(DTC2)}$	Input threshold voltage (DTC2) (see NOte 3)	Duty = 0%	f_{OSC} = 500 kHz	0.3	0.4	0.5	V
$V_{T100(DTC2)}$		Duty = 100%		0.9	1	1.1	

NOTES: 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.
3. These specifications are not production tested. They are specified as ensured values on circuit design.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V (unless otherwise noted) (see Note 1) (continued)

error amplifier section

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	CH1, 3,	A_V = 1			15	mV
I_{IB}	Input bias current	CH1, 3,	V_I = –.95 V to 1.55 V		±10	±20	nA
		CH2,	V_I = 0.4 V to 1 V		±10	±20	
V_{IR}	Input voltage range	CH1, 3,		0.95		1.55	V
		CH2		0.4		1	
A_{VD}	Open-loop voltage amplification	R_{FB} = 200 kΩ			60		dB
B_1	Unity-gain bandwidth				1		MHz
V_{OM+}	Output voltage swing	V_{ID} = 0.1 V	I_O = 60 µA	1.2			V
$V_{OM–}$			I_O = 0.2 mA			0.2	
I_{OM+}	Output sink current	V_{ID} = 0.1 V,	V_O = 0.2 V	0.2	1		mA
$I_{OM–}$	Output source current	V_{ID} = 0.1 V,	V_O = 1.2 V	–60	–100		µA
V_{T4}	Input bias voltage	CH2,	A_V = 1, T_A = 25°C	678	700	722	mV
		CH2,	A_V = 1	665	700	735	

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

output section

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_O = 20 mA (CH2)	2.9	3.05		V
		I_O = –40 mA (CH1, 3)	1.9	2.2	2.6	
V_{OL}	Low-level output voltage	I_O = 20 mA (CH1, 3)		0.2	0.4	V
		I_O = 40 mA (CH2)	0.2	0.3	0.6	
t_r	Rise time	CL = 1000 pF		130		ns
t_f	Fall time	I_O = 1000 pF		50		ns

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

total device

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CC}	Supply current	Output OFF state		2.5	4	mA
I_{CCA}	Average supply current	F_{OSC} = 500 kHz, Duty = 50%, No load		3.5	5	mA

NOTE 1: Typical values of all parameters except for $V_{REF(dev)}$ and f_{dT} are specified at T_A = 25°C.

TYPICAL CHARACTERISTICS

REFERENCE VOLTAGE vs FREE-AIR TEMPERATURE

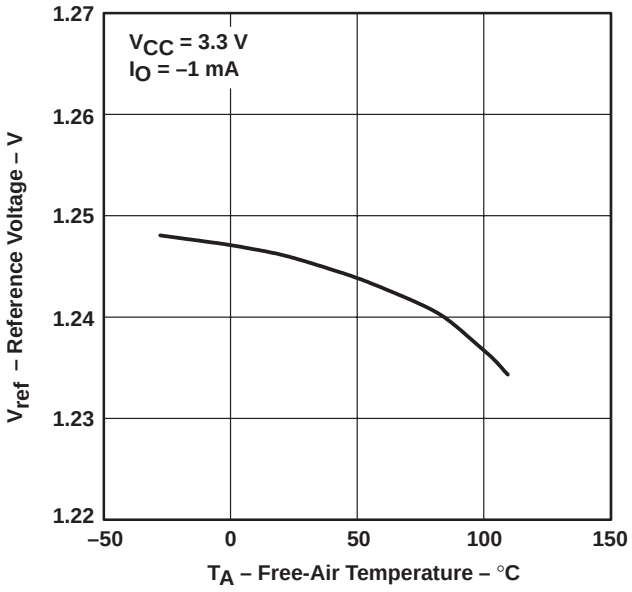


Figure 1

INPUT THRESHOLD VOLTAGE (UVLO) vs FREE-AIR TEMPERATURE

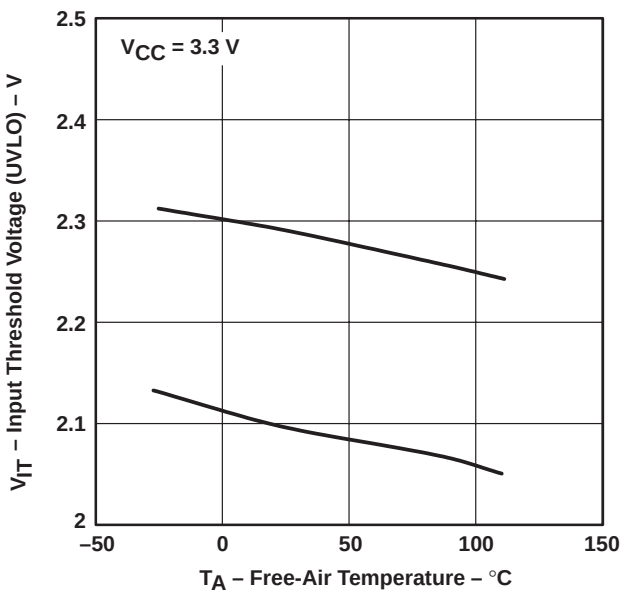


Figure 2

SUPPLY CURRENT vs FREE-AIR TEMPERATURE

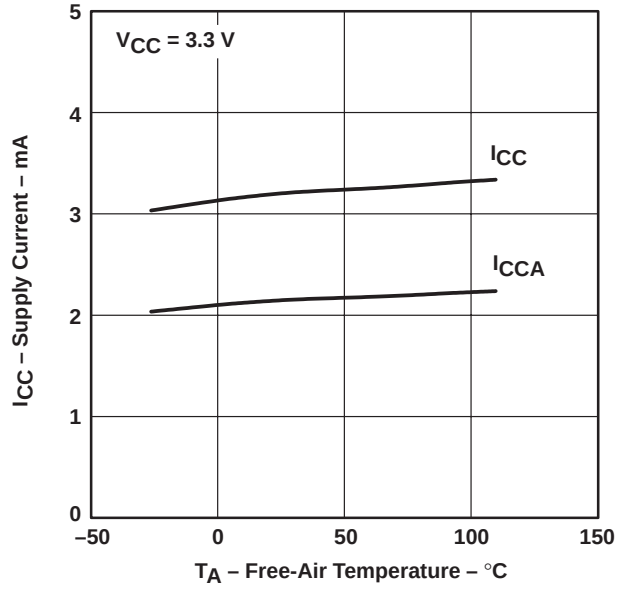


Figure 3

SOURCE CURRENT vs FREE-AIR TEMPERATURE

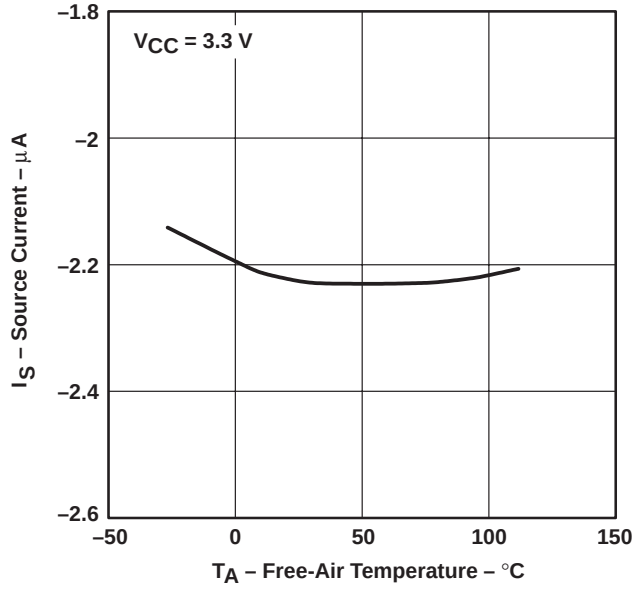


Figure 4

TYPICAL CHARACTERISTICS

OSCILLATOR FREQUENCY vs TIMING CAPACITOR

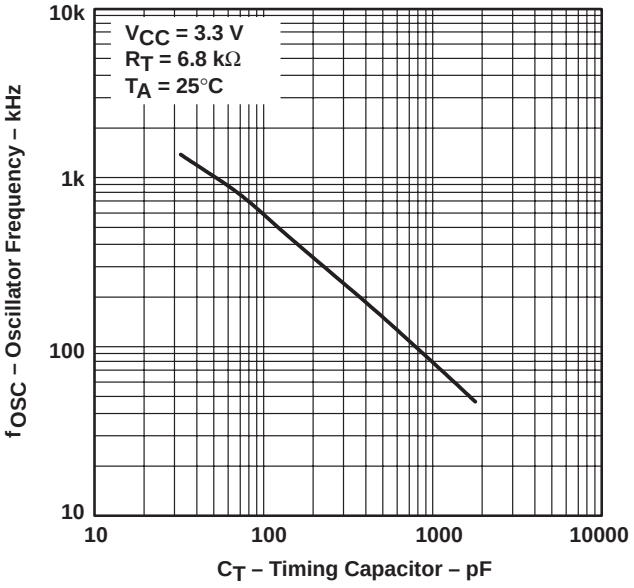


Figure 5

OSCILLATOR FREQUENCY vs FREE-AIR TEMPERATURE

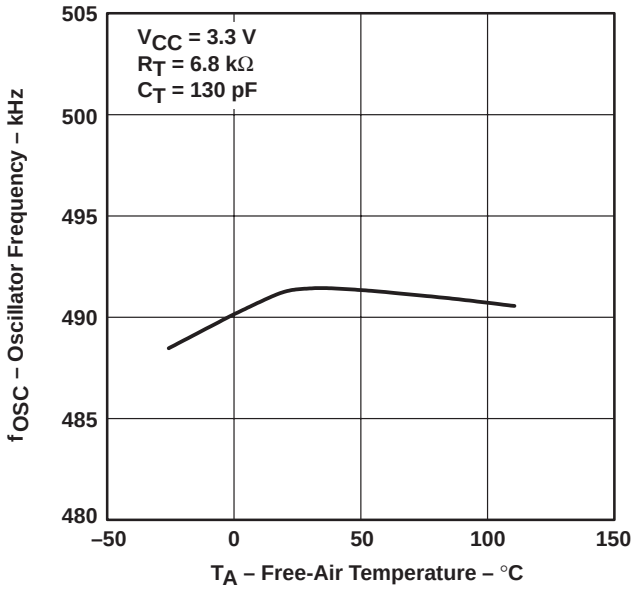


Figure 6

SOURCE CURRENT vs FREE-AIR TEMPERATURE

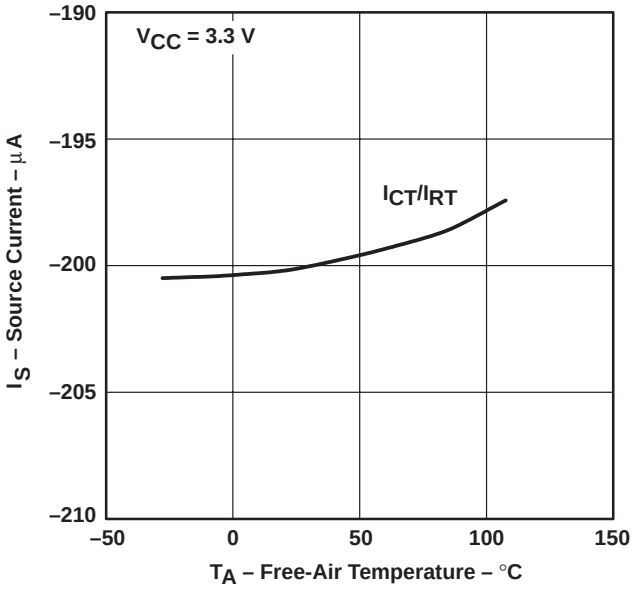


Figure 7

TYPICAL CHARACTERISTICS

INPUT THRESHOLD VOLTAGE (DTC)
vs
TIMING CAPACITOR

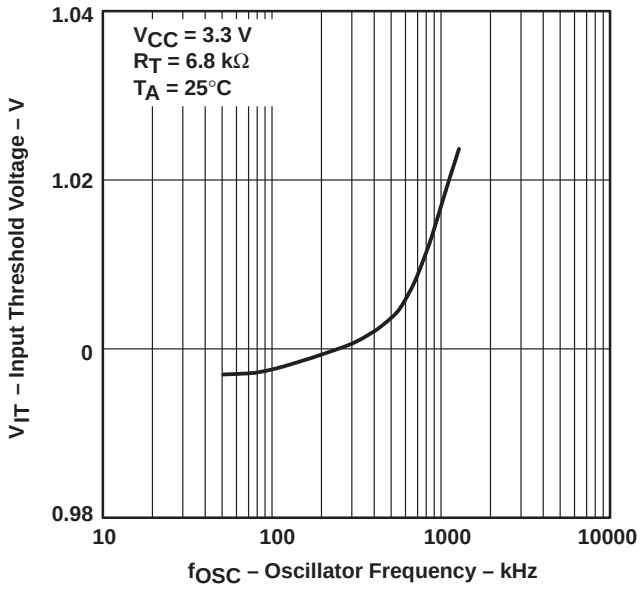


Figure 8

INPUT THRESHOLD VOLTAGE (DTC)
vs
TIMING CAPACITOR

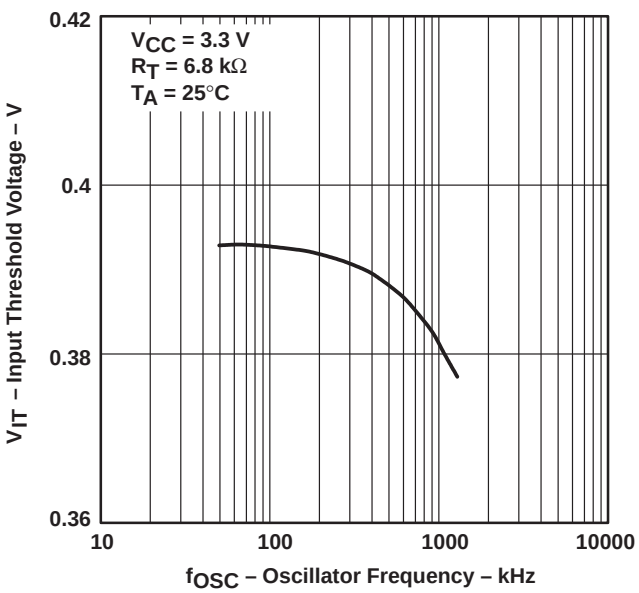


Figure 9

OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

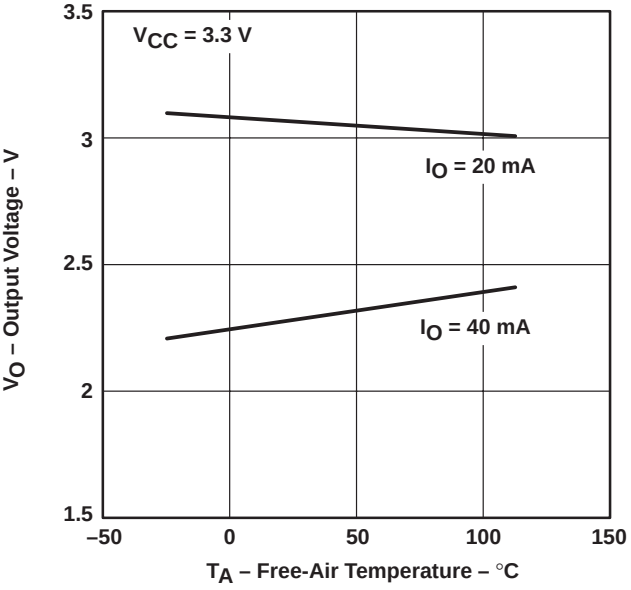


Figure 10

OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

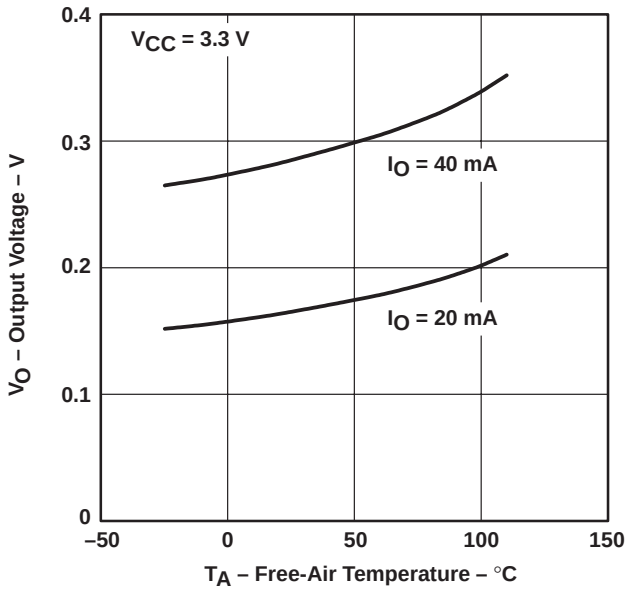


Figure 11

TYPICAL CHARACTERISTICS

MAXIMUM PEAK OUTPUT VOLTAGE
vs
OUTPUT SOURCE CURRENT

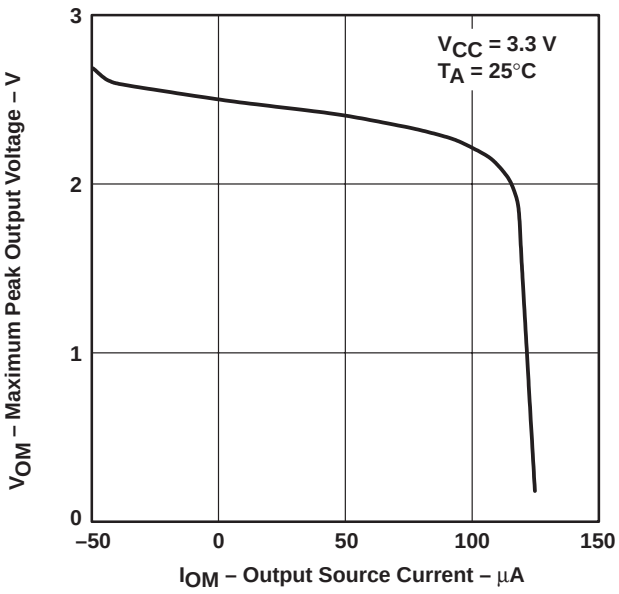


Figure 12

OUTPUT VOLTAGE
vs
SUPPLY VOLTAGE

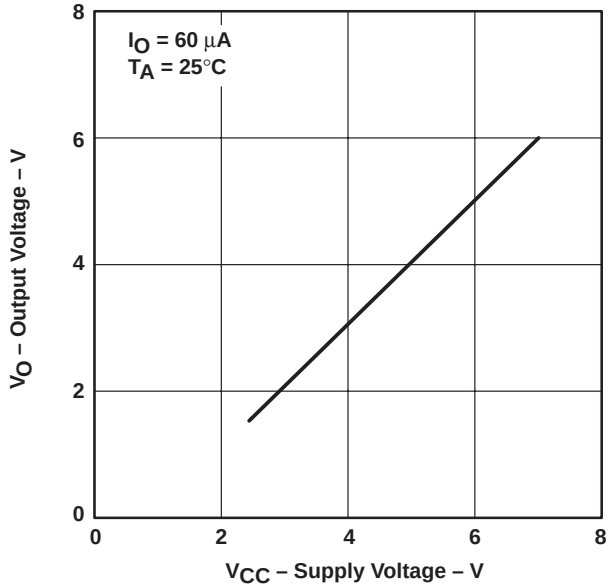


Figure 13

OUTPUT VOLTAGE
vs
OUTPUT CURRENT

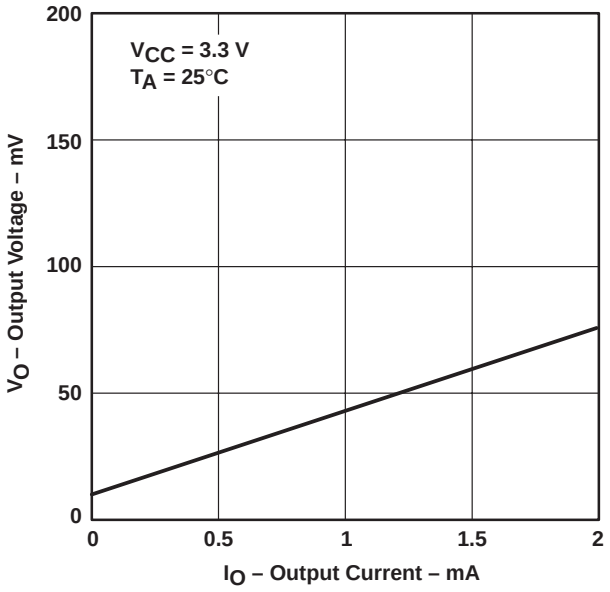


Figure 14

REFERENCE VOLTAGE
vs
SUPPLY VOLTAGE

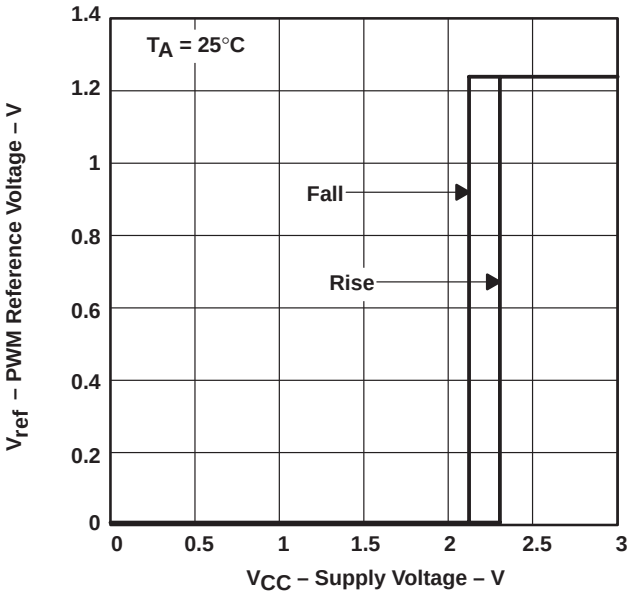


Figure 15

TYPICAL CHARACTERISTICS

**OPEN-LOOP GAIN
vs
FREQUENCY**

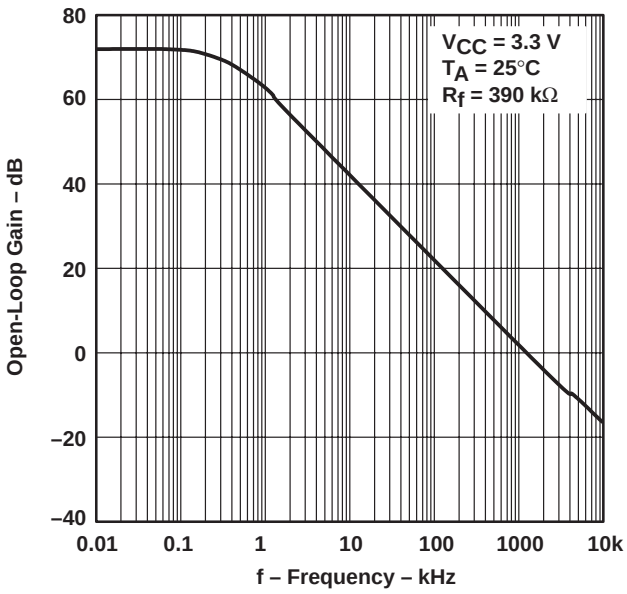


Figure 16

**PHASE SHIFT
vs
FREQUENCY**

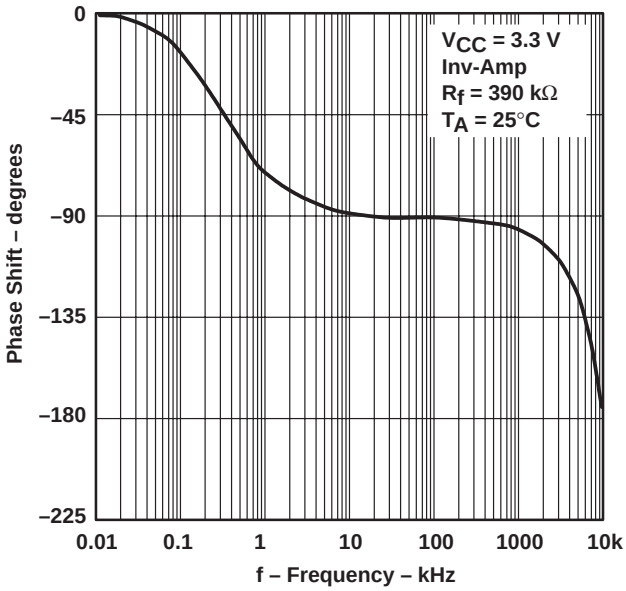
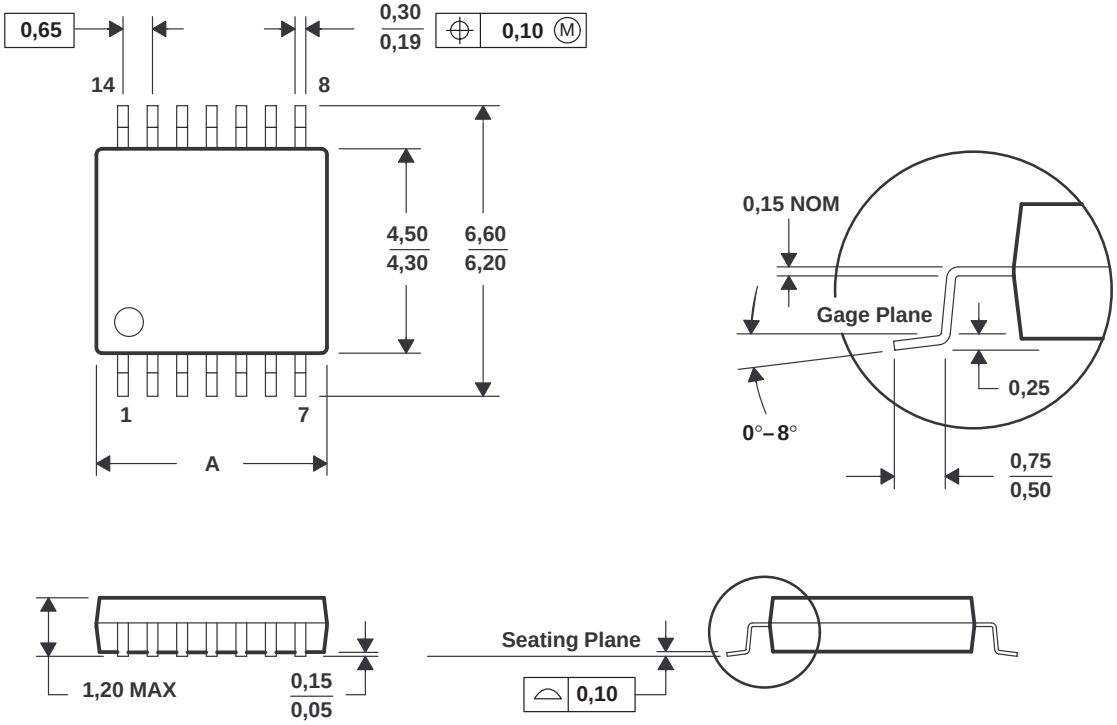


Figure 17

MECHANICAL DATA

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PIN SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/E 08/96

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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